

L Number	Hits	Search Text	DB	Time stamp
1	3	5502320.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/07 14:00
2	32	(("6221721") or ("6069043") or ("6051488") or ("6051468") or ("6015737") or ("5897343") or ("5776812") or ("5021355") or ("4983535") or ("5861649") or ("5877528") or ("6072214") or ("5502320")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/07 14:57
3	13	((("6221721") or ("6069043") or ("6051488") or ("6051468") or ("6015737") or ("5897343") or ("5776812") or ("5021355") or ("4983535") or ("5861649") or ("5877528") or ("6072214") or ("5502320")).PN.	USPAT	2002/02/07 16:06
4	2	((("5502320") or ("5986304")) .PN.	USPAT	2002/02/07 16:07
5	0	("common adj source and trench adj gate").PN.	USPAT	2002/02/07 16:07
6	36	common adj source and trench adj gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/07 16:08
-	0	257/\$5.ccls. and breakdown and avalanche and low adj on adj resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/07 14:00
-	0	257/\$5.ccls. and breakdown and low adj on adj resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 07:58
-	321	257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 07:59
-	15	257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3 and avalanche and trench	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 07:59
-	15	257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3 and avalanche and trench and power	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 08:10
-	0	(257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3 and avalanche and trench and power) and hamada.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 08:00
-	8	257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3 and avalanche and trench and power and igbt	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 08:35
-	3	257/\$5.ccls. and breakdown and low adj2 resistance and latch\$3 and avalanche and trench and power and igbt and rie	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 08:37
-	562	vertical near4 mosfet.ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 13:15

-	0	vertical near4 mosfet.ti. and drift adj drain.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 13:15
-	0	vertical near4 mosfet.ti. and drift adj2 drain	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 13:15
-	7	vertical near4 mosfet.ti. and (drift near4 drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 13:15
-	36	semiconducting adj polymer same polyaniline	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 16:53
-	0	semiconducting adj polymer same polyaniline and 106/\$5.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/10/01 16:53
-	356	("257/329").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33
-	568	("257/330").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33
-	280	("257/331").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33
-	239	("257/332").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33
-	525	("257/341").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33
-	284	("257/342").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:33
-	1013	("257/401").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:39
-	79	("257/135").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:39
-	124	("257/491").CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:39

-	329	((("257/401").CCLS.) or ((257/135").CCLS.) or ((257/491").CCLS.) or ((257/492").CCLS.) or ((257/493").CCLS.) or ((438/212").CCLS.) or ((438/259").CCLS.) or ((438/270").CCLS.) or ((438/271").CCLS.) or ((438/587").CCLS.)) and (groove or trench) adj2 gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:54
-	81	((("257/401").CCLS.) or ((257/135").CCLS.) or ((257/491").CCLS.) or ((257/492").CCLS.) or ((257/493").CCLS.) or ((438/212").CCLS.) or ((438/259").CCLS.) or ((438/270").CCLS.) or ((438/271").CCLS.) or ((438/587").CCLS.)) and (groove or trench) adj2 gate) and base adj2 (region or layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 13:56
-	81	((("257/401").CCLS.) or ((257/135").CCLS.) or ((257/491").CCLS.) or ((257/492").CCLS.) or ((257/493").CCLS.) or ((438/212").CCLS.) or ((438/259").CCLS.) or ((438/270").CCLS.) or ((438/271").CCLS.) or ((438/587").CCLS.)) and (groove or trench) adj2 gate) and (n-base or p-base or p adj base or n adj base or base) adj2 (region or layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:31
-	24	hamada.in. and trench	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:38
-	3071	((trench or groove) near3 gate)	EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:39
-	629	((trench or groove) near3 gate) and conduct\$5 and semiconduct\$5	EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:40
-	612	((trench or groove) near3 gate) and conduct\$5 and semiconduct\$5.ti,ab.	EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:40
-	598	((trench or groove) near3 gate).ti,ab. and conduct\$5 and semiconduct\$5.ti,ab.	EPO; JPO; DERWENT; IBM TDB	2002/02/01 14:49
-	120	((trench or groove) near3 gate).ti,ab. and conduct\$5 and semiconduct\$5.ti,ab. and connect\$3	EPO; JPO; DERWENT; IBM TDB	2002/02/01 15:51
-	1	5861649.pn.	USPAT	2002/02/07 11:35
-	1	6118150.pn.	EPO; JPO; DERWENT; IBM TDB	2002/02/01 15:12
-	1	6118150.pn.	USPAT	2002/02/01 15:12
-	3	herzer.in. and trench	EPO; JPO; DERWENT; IBM TDB	2002/02/01 16:47
-	8	(("6163051") or ("6118150") or ("6072214")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/02/01 17:24
-	3	(("6163051") or ("6118150") or ("6072214")).PN.	USPAT	2002/02/01 17:25
-	1	6096608.pn.	USPAT	2002/02/07 11:43
-	1	5648670.pn.	USPAT	2002/02/07 11:36
-	1	6163051.pn.	USPAT	2002/02/07 11:43